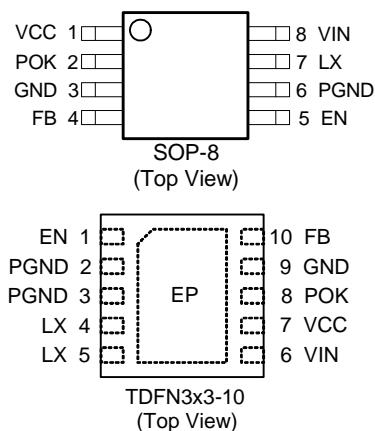


2A, 5V, 1MHz Synchronous Buck Converter

Features

- **High Efficiency up to 94%**
- **Adjustable Output Voltage from 0.8V to V_{PVDD}**
- **Operating from 2.9 to 6V Supply**
- **Integrated 85mW High Side / 75mW Low Side MOSFETs**
- **Low Dropout Operation: 100% Duty Cycle**
- **Stable with Low ESR Ceramic Capacitors**
- **Current up to 2A**
- **Power-On-Reset Detection on VCC and VIN**
- **Mode Selection :**
 - APW7322 : Automatic PFM/PWM**
 - APW7322A : Forced PWM**
- **Integrate Soft-Start and Soft-Stop**
- **Over-Temperature Protection**
- **Over-Voltage Protection**
- **Under-Voltage Protection**
- **High/ Low Side Current Limit**
- **Power Good Indication**
- **Enable/Shutdown Function**
- **Available in SOP-8P and TDFN3x3-10 Packages**
- **Lead Free and Green Devices Available (RoHS Compliant)**

Pin Configuration**General Description**

APW7322/A is a synchronous buck converters with integrated 85mΩ high side and 75mΩ low side power MOSFETs. The APW7322/A with a current-mode control scheme can convert wide input voltage of 2.9V to 6V to the output voltage adjustable from 0.8V to 6V to provide excellent output voltage regulation.

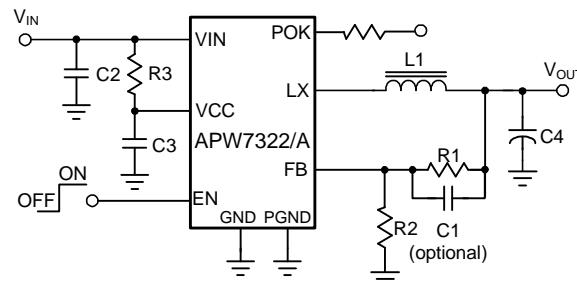
The APW7322/A is equipped with an automatic Skip/PWM mode operation. At light load , the IC operates in the Skip mode to reduce the switching losses. At heavy load, the IC works in PWM mode.

The APW7322/A is also equipped with Power-on-reset, soft start, soft-stop, and whole protections (under-voltage, over-voltage, over-temperature and current-limit) into a single package.

This device, available in SOP-8, TDFN3x3-10 packages, provides a very compact system solution external components and PCB area.

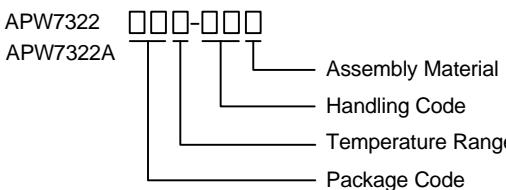
Applications

- **Notebook Computer & UMPC**
- **LCD Monitor/TV**
- **Set-Top Box**
- **DSL, Switch HUB**
- **Portable Instrument**

Simplified Application Circuit

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

Ordering and Marking Information

| | |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|  APW7322  APW7322A  | Package Code K : SOP-8 QB : TDFN3x3-10 Operating Ambient Temperature Range I : -40 to 85 °C Handling Code TR : Tape & Reel Assembly Material G : Halogen and Lead Free Device |
| APW7322 K:  APW7322 QB:  | APW7322A K:  APW7322A QB:  |
| XXXXX - Date Code | XXXXX - Date Code |

Note: ANPEC lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020D for MSL classification at lead-free peak reflow temperature. ANPEC defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

Absolute Maximum Ratings (Note 1)

| Symbol | Parameter | | Rating | Unit |
|-----------------------------------|------------------------------------------------|------------|---------------------------|------|
| V _{IN} , V _{CC} | VIN and VCC Input Voltage | | -0.3 ~ 7 | V |
| V _{LX} | LX to GND Voltage | >20ns | -1 ~ V _{IN} +0.3 | V |
| | | <20ns | V _{PGND} -5V ~9V | |
| FB, EN, POK to GND Voltage | | -0.3 ~ 6.5 | | V |
| P _D | Power Dissipation | | Internally Limited | W |
| T _J | Junction Temperature | | 150 | °C |
| T _{STG} | Storage Temperature | | -65 ~ 150 | °C |
| T _{SDR} | Maximum Lead Soldering Temperature(10 Seconds) | | 260 | °C |

Note1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Thermal Characteristics

| Symbol | Parameter | Typical Value | Unit |
|-----------------|---------------------------------------------------------------------------------------|---------------|------|
| θ _{JA} | Junction-to-Ambient Resistance in Free Air ^(Note 2) SOP-8 TDFN3x3-10 | 150 50 | °C/W |
| θ _{JC} | Junction-to-Case Resistance in Free Air ^(Note 3) SOP-8 TDFN3x3-10 | 20 6 | °C/W |

Note 2: θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. The exposed pad of SOP-8 and TDFN3x3-10 is soldered directly on the PCB.

Note 3: The case temperature is measured at the center of the exposed pad on the underside of the SOP-8 package.

Recommended Operating Conditions (Note 4)

| Symbol | Parameter | Range | Unit |
|-----------|--------------------------|-----------|-------------|
| V_{CC} | VCC Supply Voltage | 2.9~6 | V |
| V_{IN} | VIN Supply Voltage | 2.6~6 | V |
| V_{OUT} | Converter Output Voltage | 0.8~6 | V |
| L | Inductance | 1~4.7 | μH |
| C_{OUT} | Output Capacitor | 10~220 | μF |
| I_{OUT} | Converter Output Current | 0~2 | A |
| T_A | Ambient Temperature | -40 ~ 85 | $^{\circ}C$ |
| T_J | Junction Temperature | -40 ~ 125 | $^{\circ}C$ |

Note 4: Refer to the typical application circuit.

Electrical Characteristics

Unless otherwise specified, these specifications apply over $V_{CC}=V_{IN}=5V$, $V_{OUT}=3.3V$ and $T_A=-40\sim85^{\circ}C$. Typical values are at $T_A=25^{\circ}C$.

| Symbol | Parameter | Test Conditions | APW7322/A | | | Unit |
|----------------------------------|-------------------------------|--------------------------------------------------------|-----------|------|------|-----------|
| | | | Min. | Typ. | Max. | |
| SUPPLY CURRENT | | | | | | |
| I_{VCC} | VCC Supply Current | $V_{FB}=0.7V$ | - | 460 | - | μA |
| I_{VCC_SDH} | VCC Shutdown Supply Current | EN=GND | - | - | 40 | μA |
| POWER-ON-RESET (POR) | | | | | | |
| | VCC POR Voltage Threshold | V_{CC} Rising | - | 2.7 | - | V |
| | VCC POR Voltage Hysteresis | V_{CC} Falling | - | 200 | - | mV |
| | VCC Debounce Time | | - | 10 | - | μs |
| | VIN POR Voltage Threshold | V_{IN} Rising | - | 2.3 | - | V |
| | VIN POR Voltage Hysteresis | V_{IN} Falling | - | 50 | - | mV |
| REFERENCE VOLTAGE | | | | | | |
| V_{REF} | Reference Voltage | | - | 0.8 | - | V |
| | | All temperature | -1 | - | +1 | % |
| | Output Accuracy | $I_{OUT}=10mA\sim3A$, $V_{CC}=2.9\sim5V$ | -1.5 | - | +1.5 | % |
| OSCILLATOR and DUTY CYCLE | | | | | | |
| F_{OSC} | Oscillator Frequency | | 0.85 | 1 | 1.15 | MHz |
| | Maximum Converter's Duty | $V_{FB}=0.7V$ | - | 100 | - | % |
| | Minimum on Time | | - | 70 | - | ns |
| POWER MOSFET | | | | | | |
| | High Side P-MOSFET Resistance | $V_{CC}=V_{IN}=5V$, $I_{LX}=0.5A$, $T_A=25^{\circ}C$ | - | 85 | 115 | $m\Omega$ |
| | Low Side N-MOSFET Resistance | $V_{CC}=V_{IN}=5V$, $I_{LX}=0.5A$, $T_A=25^{\circ}C$ | - | 75 | 105 | $m\Omega$ |

Electrical Characteristics (Cont.)

Unless otherwise specified, these specifications apply over $V_{CC}=V_{IN}=5V$, $V_{OUT}=3.3V$ and $T_A=-40\sim85^\circ C$. Typical values are at $T_A=25^\circ C$.

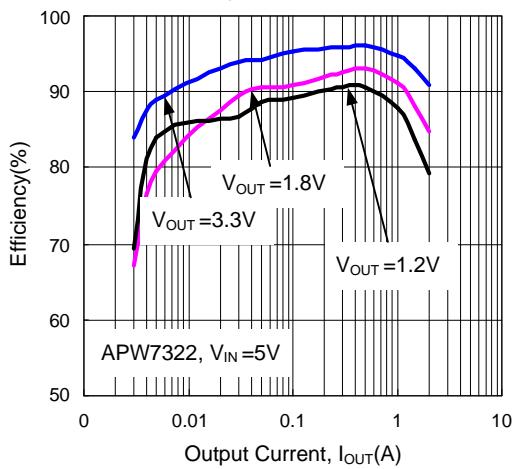
| Symbol | Parameter | Test Conditions | APW7322/A | | | Unit |
|----------------------------------------------|---------------------------------------------------------|----------------------|-----------|-------|------|-------------|
| | | | Min. | Typ. | Max. | |
| CURRENT -MODE PWM CONVERTER | | | | | | |
| Gm | Error Amplifier Transconductance | | - | 680 | - | $\mu A/V$ |
| | Error Amplifier DC Gain | COMP=NC | - | 50 | - | dB |
| | Current Sense Resistance | | - | 400 | - | $m\Omega$ |
| T_D | Dead Time | | - | 20 | - | ns |
| PROTECTIONS | | | | | | |
| I_{LIM} | High Side MOSFET Current-Limit | Peak Current | 3 | 4 | 5 | A |
| T_{OTP} | Over-temperature Trip Point (Re-softstart after OTP) | | - | 160 | - | $^\circ C$ |
| | Over-temperature Hysteresis | | - | 50 | - | $^\circ C$ |
| | Over- Voltage Protection Threshold | | 120 | 125 | 130 | $\%V_{REF}$ |
| | OVP Debounce Time | | - | 3 | - | μs |
| | Under-Voltage Protection Threshold | | 45 | 50 | 55 | $\%V_{REF}$ |
| | UVP Debounce Time | | - | 3 | - | μs |
| | Low Side Switch Current-Limit | From Drain to Source | - | -1.9 | - | A |
| SOFT-START, ENABLE and INPUT CURRENTS | | | | | | |
| | Soft Start time | | - | 2.5 | - | ms |
| | EN Enable Threshold Voltage | V_{EN} Rising | 0.8 | - | 1.3 | V |
| | EN Threshold Hysteresis | | - | 0.2 | - | V |
| | EN Pull High Resistance | | - | 300 | - | $k\Omega$ |
| POWER GOOD | | | | | | |
| POK Threshold | POK in from lower (POK goes high) | | 85 | 87.5 | 90 | $\%V_{OUT}$ |
| | POK low hysteresis | | - | 5 | - | $\%V_{OUT}$ |
| | POK in from higher (POK goes high) | | 110 | 112.5 | 115 | $\%V_{OUT}$ |
| | POK high hysteresis | | - | 5 | - | $\%V_{OUT}$ |
| | POK Pull Low Resistance | | - | 1 | - | $k\Omega$ |
| | POK Low-to-High Debounce Time | | - | 0.5 | - | ms |

Pin Description

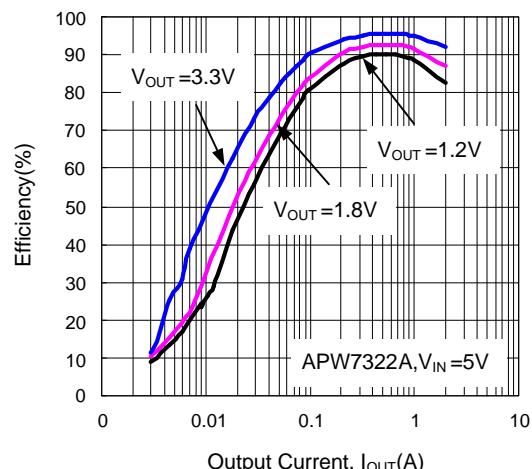
| Pin | | | Function |
|-------|------------|-------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NO. | | Name | |
| SOP-8 | TDFN3x3-10 | | |
| 1 | 7 | VCC | Signal Input. VCC supplies the control circuitry, gate drivers. Connecting a ceramic bypass capacitor from VCC to GND to eliminate switching noise and voltage ripple on the input to the IC. |
| 2 | 8 | POK | Power Good Output. This pin is open-drain logic output that is pulled to ground when the output voltage is not within $\pm 2.5\%$ of regulation point. The POK pin, if used, needs an external pull high resistor in the range of $30k\Omega \sim 100k\Omega$. |
| 3 | 9 | GND | Ground. Power and signal ground. |
| 4 | 10 | FB | Output Feedback Input. The APW7322/A senses the feedback voltage via FB and regulates the voltage at 0.8V. Connecting FB with a resistor-divider from the converter's output sets the output voltage. |
| 5 | 1 | EN | Enable Input. EN is a digital input that turns the regulator on or off. Driving the EN high turns on the regulator, otherwise, driving it low turns it off. The EN pin is internally pulled high via a $300k\Omega$ resistor. |
| 6 | 2, 3 | PGND | Power Ground. |
| 7 | 4,5 | LX | Power Switching Output. LX is the Junction of the high-side and low-side Power MOSFETs to supply power to the output LC filter. |
| 8 | 6 | VIN | Power Input. VIN supplies the step-down converter switches. |
| 9 | 11 | Exposed Pad | Exposed pad. Connect the exposed pad to the system ground plan with large copper area for dissipating heat into the ambient air. |

Typical Operating Characteristics

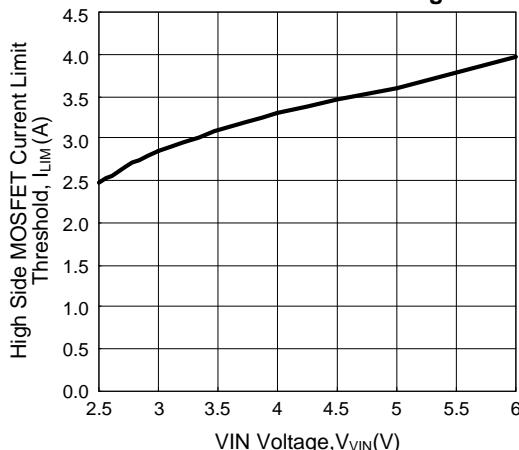
Efficiency vs. Output Current



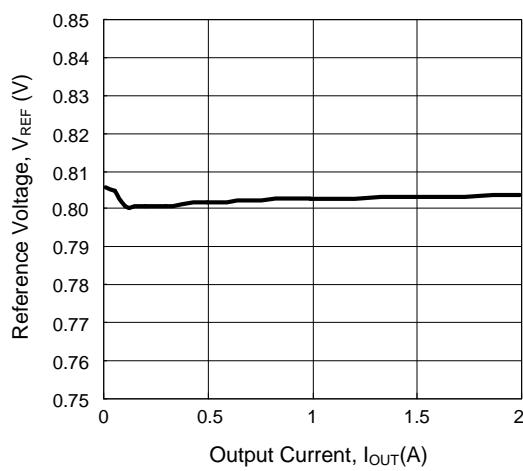
Efficiency vs. Output Current



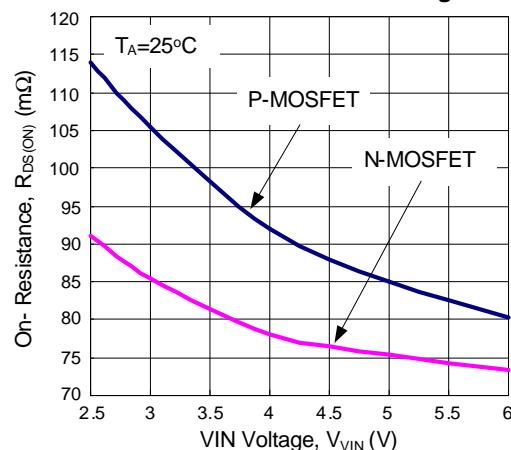
High Side MOSFET Current Limit Threshold vs. VIN Voltage



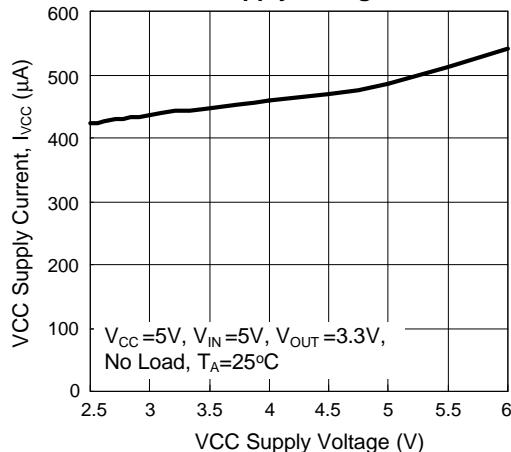
Reference Voltage vs. Output Current



On-Resistance vs. VIN Voltage



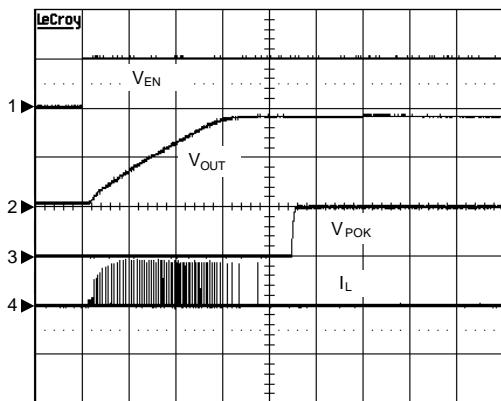
VCC Supply Current vs. VCC Supply Voltage



Operating Waveforms

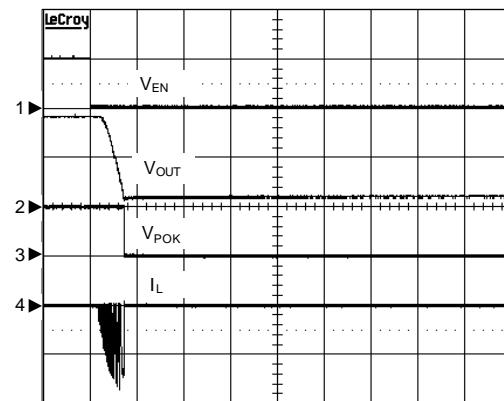
The test condition is APW7322, $V_{IN}=V_{CC}=5V$, $V_{OUT}=1.8V$, $C_{OUT}=22\mu F \times 2$, $L=2.2\mu H$, $T_A=25^\circ C$ unless otherwise specified.

Enable without Loading



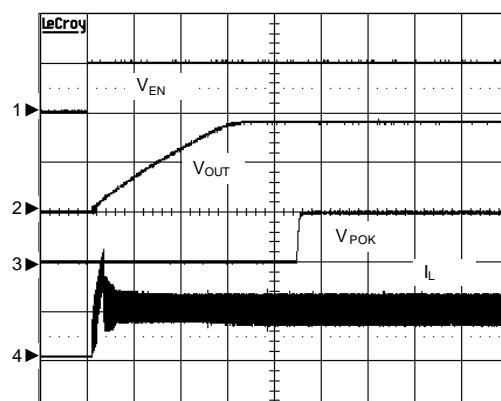
No load, Enable Power On
 CH1: V_{EN} , 5V/Div, DC
 CH2: V_{OUT} , 1V/Div, DC
 CH3: V_{POK} , 5V/Div, DC
 CH4: I_L , 1A/Div, DC
 TIME: 1ms/Div

Shutdown without Loading



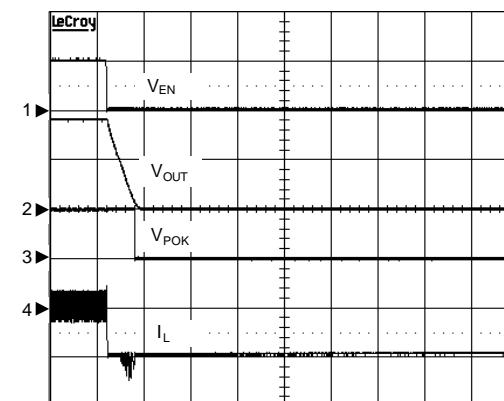
No load , Enable Power On
 CH1: V_{EN} , 5V/Div, DC
 CH2: V_{OUT} , 1V/Div, DC
 CH3: V_{POK} , 5V/Div, DC
 CH4: I_L , 1A/Div, DC
 TIME: 200μs/Div

Enable with 1A Loading



$I_{OUT}=1A$, Enable Power On
 CH1: V_{EN} , 5V/Div, DC
 CH2: V_{OUT} , 1V/Div, DC
 CH3: V_{POK} , 5V/Div, DC
 CH4: I_L , 1A/Div, DC
 TIME: 1ms/Div

Shutdown with 1A Loading

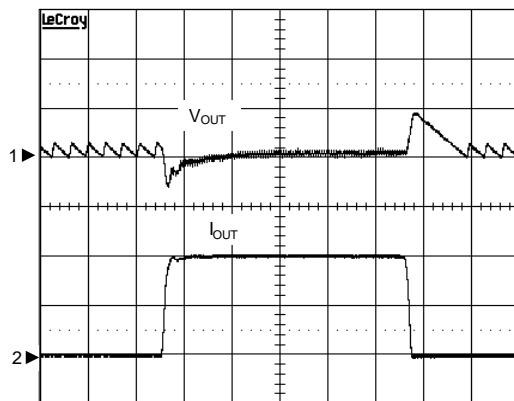


$I_{OUT}=1A$, Enable Power On
 CH1: V_{EN} , 5V/Div, DC
 CH2: V_{OUT} , 1V/Div, DC
 CH3: V_{POK} , 5V/Div, DC
 CH4: I_L , 1A/Div, DC
 TIME: 100μs/Div

Operating Waveforms

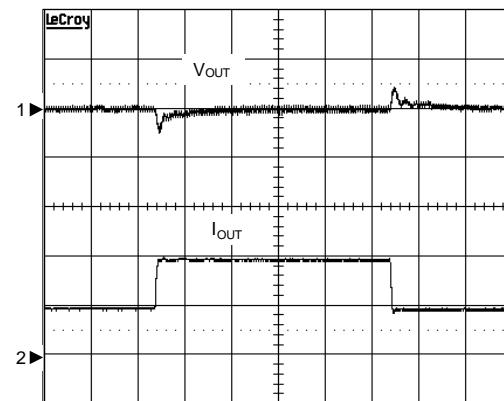
The test condition is APW7322, $V_{IN}=V_{CC}=5V$, $V_{OUT}=1.8V$, $C_{OUT}=22\mu F \times 2$, $L=2.2\mu H$, $T_A=25^\circ C$ unless otherwise specified.

Load Transient



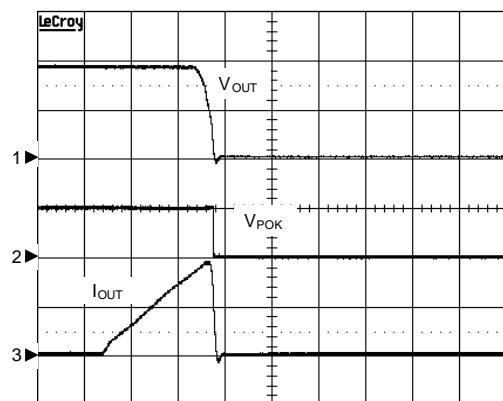
$I_{OUT}=100mA-2A-100mA$, Slew Rate=1A/μs
 CH1: V_{OUT} , 100mV/Div, offset=1.8V
 CH2: I_{OUT} , 1A/Div, DC
 TIME: 20μs/Div

Load Transient



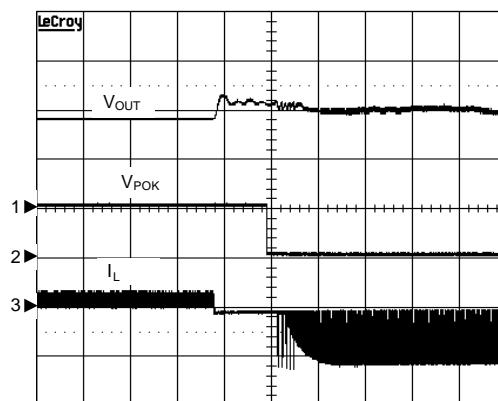
$I_{OUT}=1A-2A-1A$, Slew Rate=1A/μs
 CH1: V_{OUT} , 100mV/Div, offset=1.8V
 CH2: I_{OUT} , 1A/Div, DC
 TIME: 20μs/Div

Current Limit



CH1: V_{OUT} , 1V/Div, DC
 CH2: V_{POK} , 5V/Div, DC
 CH3: I_{OUT} , 2A/Div, DC
 TIME: 200μs/Div

Over Voltage Protection

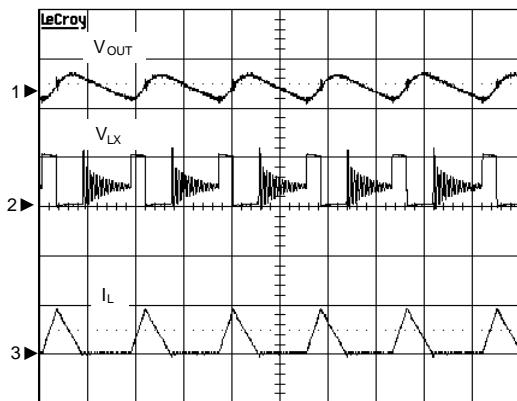


$I_{OUT}=100mA$, a 2.5V power source is externally attached to V_{OUT}
 CH1: V_{OUT} , 1V/Div, DC
 CH2: V_{POK} , 5V/Div, DC
 CH3: I_L , 2A/Div, DC
 TIME: 200μs/Div

Operating Waveforms

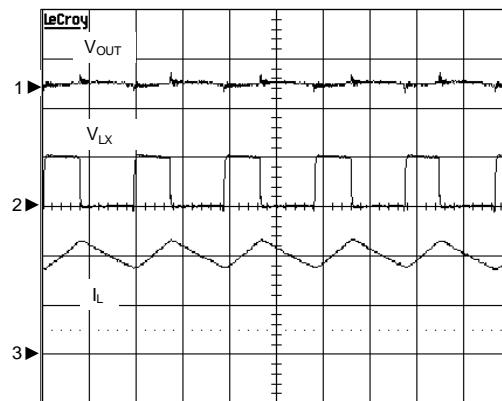
The test condition is APW7322, $V_{IN}=V_{CC}=5V$, $V_{OUT}=1.8V$, $C_{OUT}=22\mu F \times 2$, $L=2.2\mu H$, $T_A=25^\circ C$ unless otherwise specified.

Normal Operation in Ligh Load



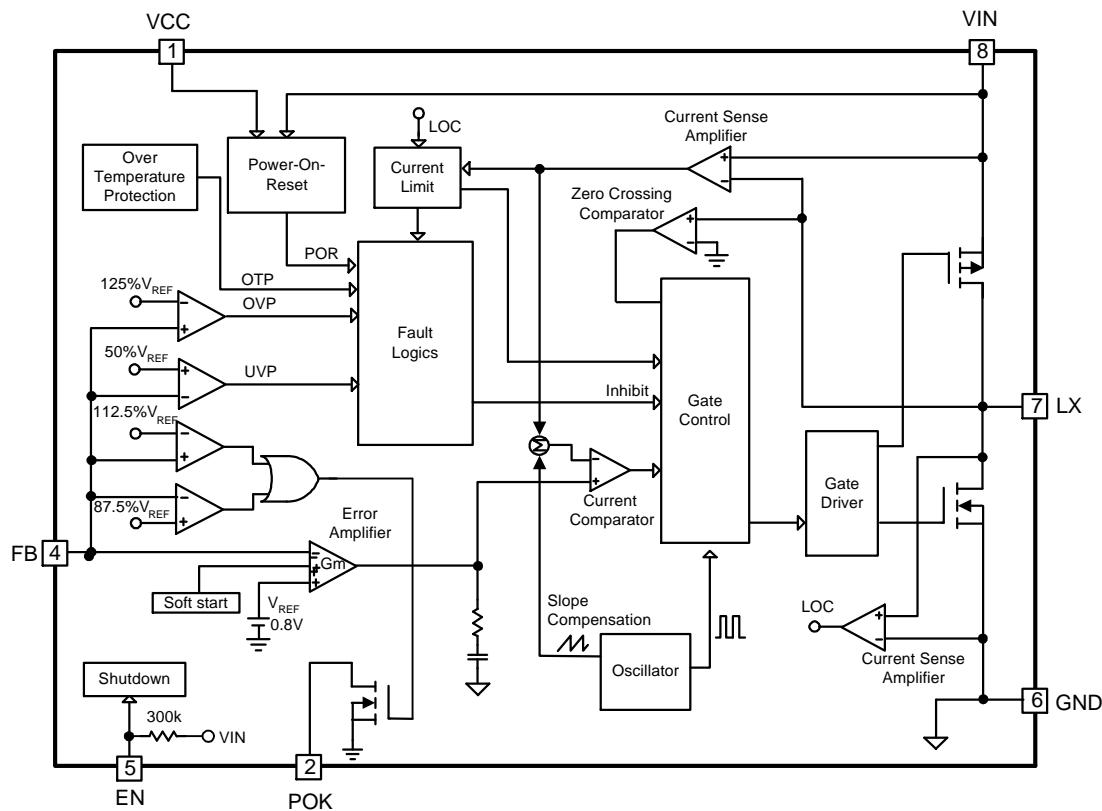
$I_{OUT}=200mA$
CH1: V_{OUT} , 50mV/Div, offset=1.8V
CH2: V_{LX} , 5V/Div, DC
CH3: I_{LX} , 1A/Div, DC
TIME: 2μs/Div

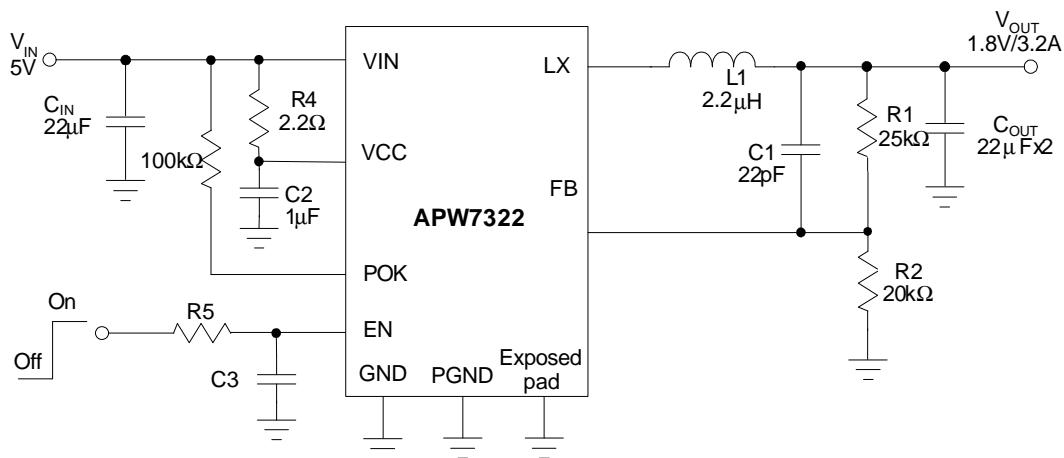
Normal Operation in Heavy Load



$I_{OUT}=2A$
CH1: V_{OUT} , 50mV/Div, offset=1.8V
CH2: V_{LX} , 5V/Div, DC
CH3: I_{LX} , 1A/Div, DC
TIME: 0.5μs/Div

Block Diagram



Typical Application Circuit

Function Description

VCC and VIN Power-On-Reset (POR)

The APW7322/A keeps monitoring the voltage on VIN and VCC pins to prevent wrong logic operations which may occur when VIN or VCC voltage is not high enough for internal control circuitry to operate. The VCC POR rising threshold is 2.7V (typical) with 0.2V hysteresis and VIN POR rising threshold is 2.3V with 0.05V hysteresis. During startup, the VCC and VIN voltage must exceed the POR threshold. Then the IC starts a start-up process and ramps up the output voltage to the voltage target.

Output Under-Voltage Protection (UVP)

In the operational process, if a short-circuit occurs, the output voltage will drop quickly. Before the current-limit circuit responds, the output voltage will fall out of the required regulation range. The under-voltage continually monitors the FB voltage after soft-start is completed. If a load step is strong enough to pull the output voltage lower than the under-voltage threshold, the IC shuts down converter's output.

The under-voltage threshold is 50% of the nominal output voltage. The under-voltage comparator has a built-in 3 μ s noise filter to prevent the chips from wrong UVP shutdown being caused by noise. The APW7322/A will be latched after under-voltage protection.

Over-Voltage Protection (OVP)

The over-voltage function monitors the output voltage by FB pin. When the FB voltage increases over 125% of the reference voltage due to the high-side MOSFET failure or for other reasons, the over-voltage protection comparator will force the low-side MOSFET gate driver high till the occurrence of low-side current limit. This action actively pulls down the output voltage. As soon as the output voltage is less than 0.2V, the APW7322/A will be latched off and needs a POR or enable to recover to normal operation.

Over-Temperature Protection (OTP)

The over-temperature circuit limits the junction temperature of the APW7322/A. When the junction temperature exceeds $T_J = 160^{\circ}\text{C}$, a thermal sensor turns off the both power MOSFETs, allowing the devices to cool.

The thermal sensor allows the converters to start a start-up process and to regulate the output voltage again after the junction temperature cools by 50°C . The OTP is designed with a 50°C hysteresis to lower the average T_J during continuous thermal overload conditions, increasing lifetime of the APW7322/A.

Current-Limit Protection

The APW7322/A monitors the output current, flows through the high-side and low-side power MOSFETs, and limits the current peak at current-limit level to prevent the IC from damaging during overload, short-circuit and over-voltage conditions. Typical high side power MOSFET current limit is 3A, and low side MOSFET current limit is 1.9A.

Soft-Start

The APW7322/A has a built-in soft-start to control the rise rate of the output voltage and limit the input current surge during start-up. During soft-start, an internal voltage ramp connected to one of the positive inputs of the error amplifier, rises up from 0V to 0.95V to replace the reference voltage (0.8V) until the voltage ramp reaches the reference voltage. During soft-start without output over-voltage, the APW7322/A converter's sinking capability is disabled until the output voltage reaches the voltage target.

Soft-Stop

At the moment of shutdown controlled by EN signal, under-voltage event or over-temperature protection, the APW7322/A initiates a soft-stop process to discharge the output voltage in the output capacitors. Certainly, the load current also discharges the output voltage. During soft-stop, the internal voltage ramp (V_{RAMP}) falls down from 0.95V to 0V to replace the reference voltage. Therefore, the output voltage falls down slowly at the light load. After the soft-stop interval elapses, the soft-stop process ends and the IC turns on the low-side power MOSFET.

Enable and Shutdown

Driving EN to ground places the APW7322/A in shutdown. In shutdown mode, the internal N-Channel power MOSFET turns off, all internal circuitry shuts down and the quiescent supply current reduces to less than 20 μA .

Function Description (Cont.)

Power Good Indicator

POK is actively held low in shutdown and soft-start status. In the soft-start process, the POK is an open-drain. When the soft-start is finished, the POK is released. In normal operation, the POK window is from 87.5% to 112.5% of the converter reference voltage. When the output voltage has to stay within this window, POK signal will become high after 0.5ms internal delay. When the output voltage outruns 82.5% or 117.5% of the target voltage, POK signal will be pulled low immediately. In order to prevent false POK drop, capacitors need to parallel at the output to confine the voltage deviation with severe load step transient. The POK pin, if used, needs an external pull high resistor, the recommended resistor should be in the range of 30KΩ to 100KΩ.

Application Information

Input Capacitor Selection

Because buck converters have a pulsating input current, a low ESR input capacitor is required. This results in the best input voltage filtering, minimizing the interference with other circuits caused by high input voltage spikes. Also, the input capacitor must be sufficiently large to stabilize the input voltage during heavy load transients. For good input voltage filtering, usually a 22 μ F input capacitor is sufficient. It can be increased without any limit for better input voltage filtering. Ceramic capacitors show better performance because of the low ESR value, and they are less sensitive against voltage transients and spikes compared to tantalum capacitors. Place the input capacitor as close as possible to the input and GND pin of the device for better performance.

Inductor Selection

For high efficiencies, the inductor should have a low dc resistance to minimize conduction losses. Especially at high-switching frequencies the core material has a higher impact on efficiency. When using small chip inductors, the efficiency is reduced mainly due to higher inductor core losses. This needs to be considered when selecting the appropriate inductor. The inductor value determines the inductor ripple current. The larger the inductor value, the smaller the inductor ripple current and the lower the conduction losses of the converter. Conversely, larger inductor values cause a slower load transient response. A reasonable starting point for setting ripple current, ΔI_L , is 40% of maximum output current. The recommended inductor value can be calculated as below:

$$L \geq \frac{V_{OUT} \left(1 - \frac{V_{OUT}}{V_{IN}} \right)}{F_{SW} \cdot \Delta I_L}$$

$$I_{L(MAX)} = I_{OUT(MAX)} + 1/2 \times DI_L$$

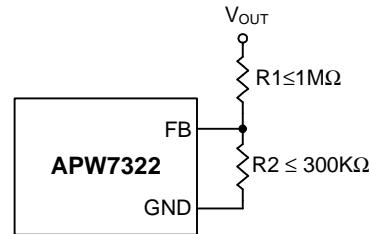
To avoid saturation of the inductor, the inductor should be rated at least for the maximum output current of the converter plus the inductor ripple current.

Output Voltage Setting

In the adjustable version, the output voltage is set by a resistive divider. The external resistive divider is connected to the output, allowing remote voltage sensing as

shown in "Typical Application Circuits". A suggestion of maximum value of R2 is 300k Ω to keep the minimum current that provides enough noise rejection ability through the resistor divider. The output voltage can be calculated as below:

$$V_{OUT} = V_{REF} \cdot \left(1 + \frac{R1}{R2} \right)$$

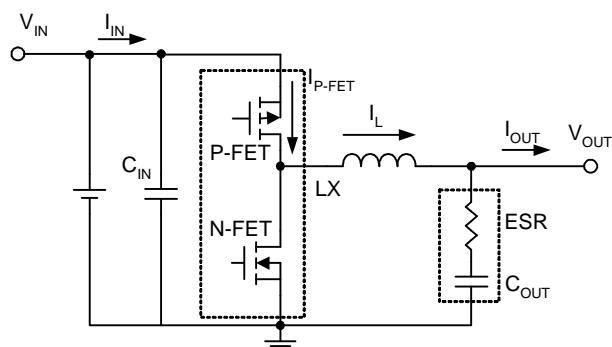


Output Capacitor Selection

The current-mode control scheme of the APW7322 allows the use of tiny ceramic capacitors. The higher capacitor value provides the good load transients response. Ceramic capacitors with low ESR values have the lowest output voltage ripple and are recommended. If required, tantalum capacitors may be used as well. The output ripple is the sum of the voltages across the ESR and the ideal output capacitor.

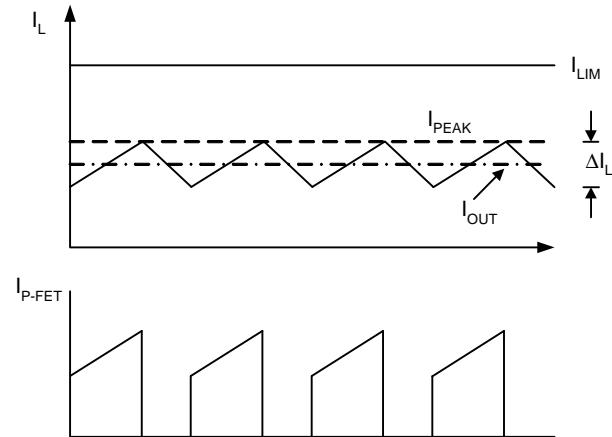
$$\Delta V_{OUT} \approx \frac{V_{OUT} \cdot \left(1 - \frac{V_{OUT}}{V_{IN}} \right)}{F_{SW} \cdot L} \cdot \left(ESR + \frac{1}{8 \cdot F_{SW} \cdot C_{OUT}} \right)$$

When choosing the input and output ceramic capacitors, choose the X5R or X7R dielectric formulations. These dielectrics have the best temperature and voltage characteristics of all the ceramics for a given value and size.

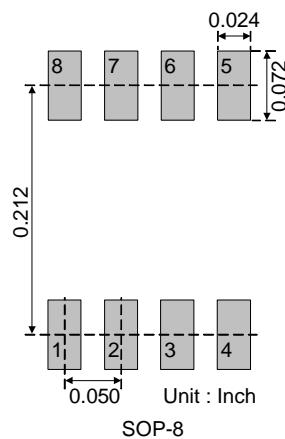


Application Information (Cont.)

Output Capacitor Selection (Cont.)



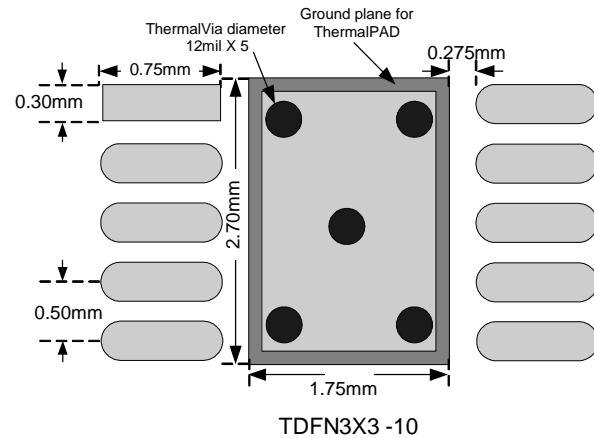
Recommended Minimum Footprint



Layout Considerations

For all switching power supplies, the layout is an important step in the design; especially at high peak currents and switching frequencies. If the layout is not carefully done, the regulator might show noise problems and duty cycle jitter.

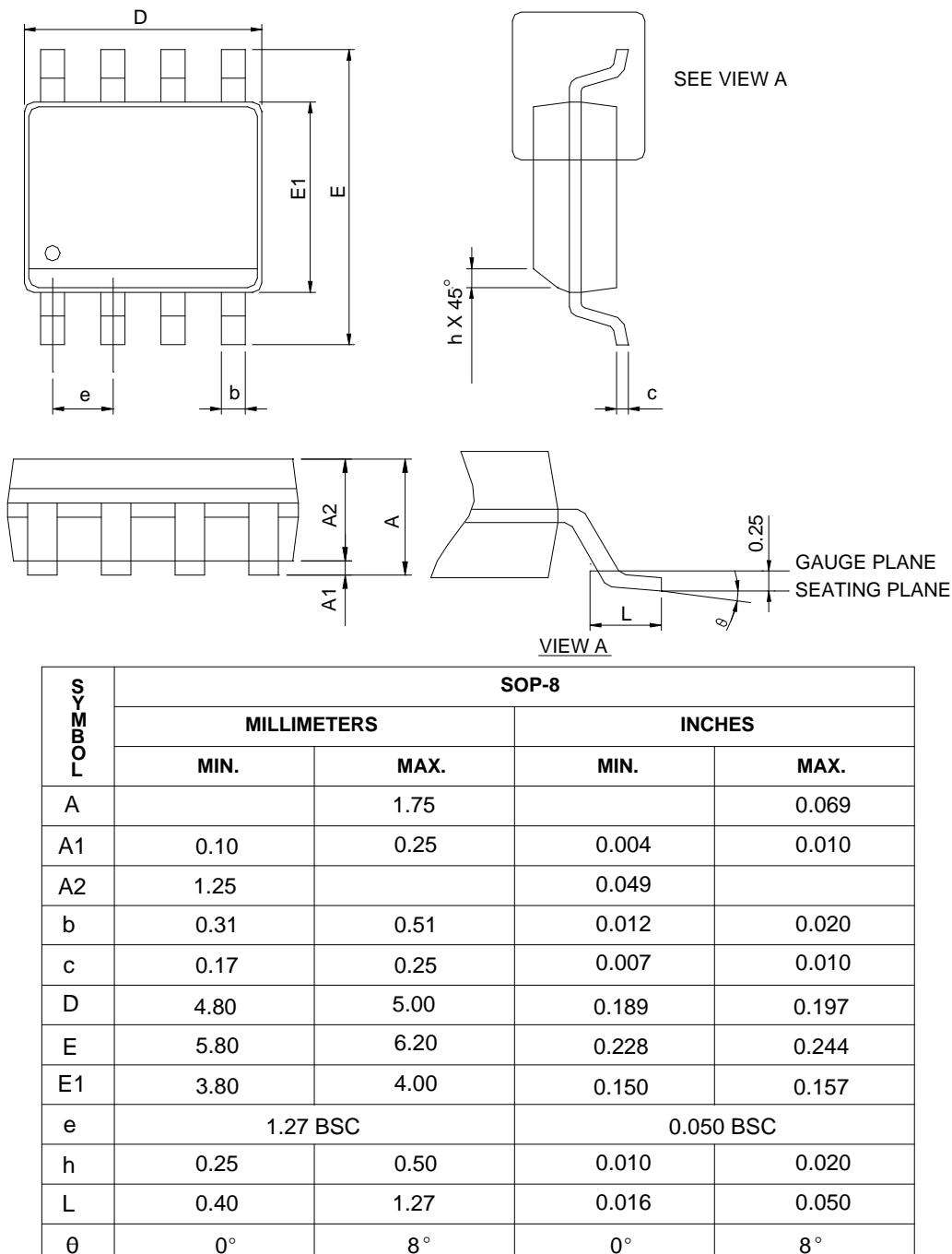
1. The input capacitor should be placed close to the VIN and GND. Connect the capacitor and VIN/GND with short and wide trace without any via holes for good input voltage filtering. The distance between VIN/GND to capacitor less than 2mm respectively is recommended.
2. To minimize copper trace connections that can inject noise into the system, the inductor should be placed as close as possible to the LX pin to minimize the noise coupling into other circuits.
3. The output capacitor should be place closed to VOUT and GND.
4. Keep the sensitive small signal nodes (FB) away from switching nodes (LX) on the PCB. Therefore place the feedback divider and the feedback compensation network close to the IC to avoid switching noise. Connect the ground of feedback divider directly to the GND pin of the IC using a dedicated ground trace.
5. A star ground connection or ground plane minimizes ground shifts and noise is recommended.



TDFN3X3 -10

Package Information

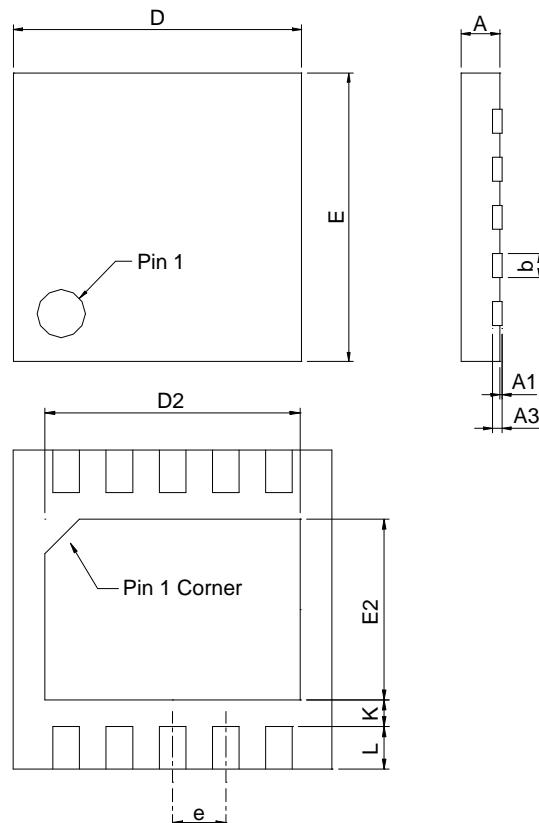
SOP-8



- Note:
- Follow JEDEC MS-012 AA.
 - Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
 - Dimension "E" does not include inter-lead flash or protrusions. Inter-lead flash and protrusions shall not exceed 10 mil per side.

Package Information

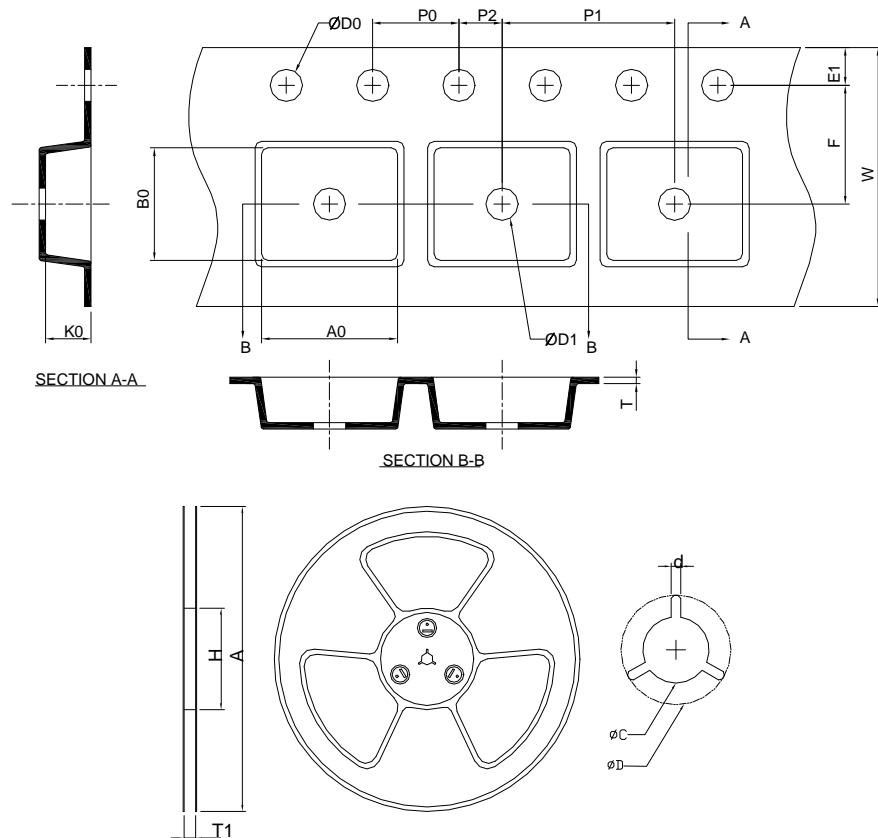
TDFN3x3-10



| SYMBOL | TDFN3x3-10 | | | |
|--------|-------------|------|-----------|-------|
| | MILLIMETERS | | INCHES | |
| | MIN. | MAX. | MIN. | MAX. |
| A | 0.70 | 0.80 | 0.028 | 0.031 |
| A1 | 0.00 | 0.05 | 0.000 | 0.002 |
| A3 | 0.20 REF | | 0.008 REF | |
| b | 0.18 | 0.30 | 0.007 | 0.012 |
| D | 2.90 | 3.10 | 0.114 | 0.122 |
| D2 | 2.20 | 2.70 | 0.087 | 0.106 |
| E | 2.90 | 3.10 | 0.114 | 0.122 |
| E2 | 1.40 | 1.75 | 0.055 | 0.069 |
| e | 0.50 BSC | | 0.020 BSC | |
| L | 0.30 | 0.50 | 0.012 | 0.020 |
| K | 0.20 | | 0.008 | |

Note : 1. Followed from JEDEC MO-229 VEED-5.

Carrier Tape & Reel Dimensions

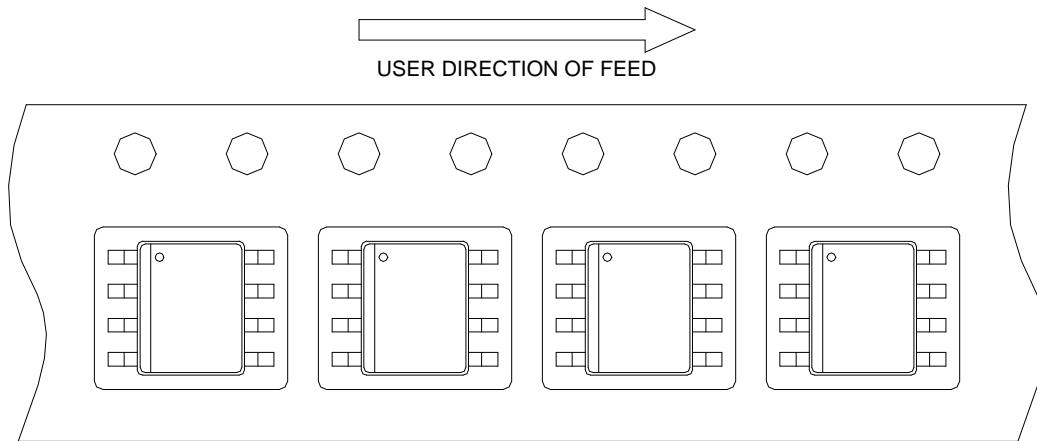
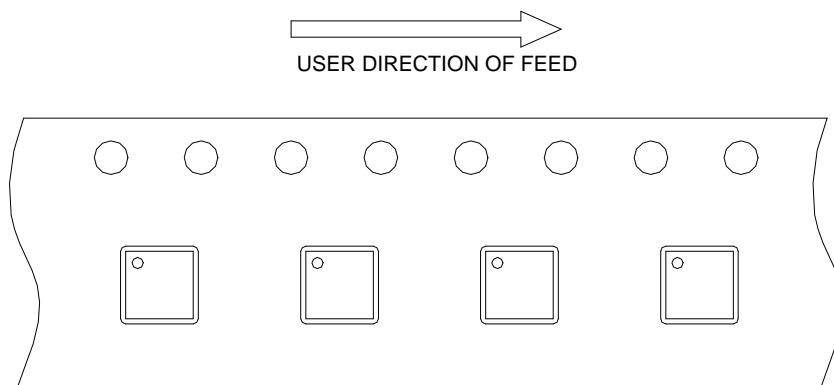


| Application | A | H | T1 | C | d | D | W | E1 | F |
|-------------|-------------|-----------|--------------------|--------------------|----------|-------------------|------------|------------|------------|
| SOP-8 | 330.0 ±0.00 | 50 MIN. | 12.4+2.00 -0.00 | 13.0+0.50 -0.20 | 1.5 MIN. | 20.2 MIN. | 12.0 ±0.30 | 1.75 ±0.10 | 5.5 ±0.05 |
| | P0 | P1 | P2 | D0 | D1 | T | A0 | B0 | K0 |
| | 4.0 ±0.10 | 8.0 ±0.10 | 2.0 ±0.05 | 1.5+0.10 -0.00 | 1.5 MIN. | 0.6+0.00 -0.40 | 6.40 ±0.20 | 5.20 ±0.20 | 2.10 ±0.20 |
| Application | A | H | T1 | C | d | D | W | E1 | F |
| TDFN3x3-10 | 330.0 ±0.00 | 50 MIN. | 12.4+2.00 -0.00 | 13.0+0.50 -0.20 | 1.5 MIN. | 20.2 MIN. | 12.0 ±0.30 | 1.75 ±0.10 | 5.5 ±0.05 |
| | P0 | P1 | P2 | D0 | D1 | T | A0 | B0 | K0 |
| | 4.0 ±0.10 | 8.0 ±0.10 | 2.0 ±0.05 | 1.5+0.10 -0.00 | 1.5 MIN. | 0.6+0.00 -0.40 | 3.30 ±0.20 | 3.30 ±0.20 | 1.30 ±0.20 |

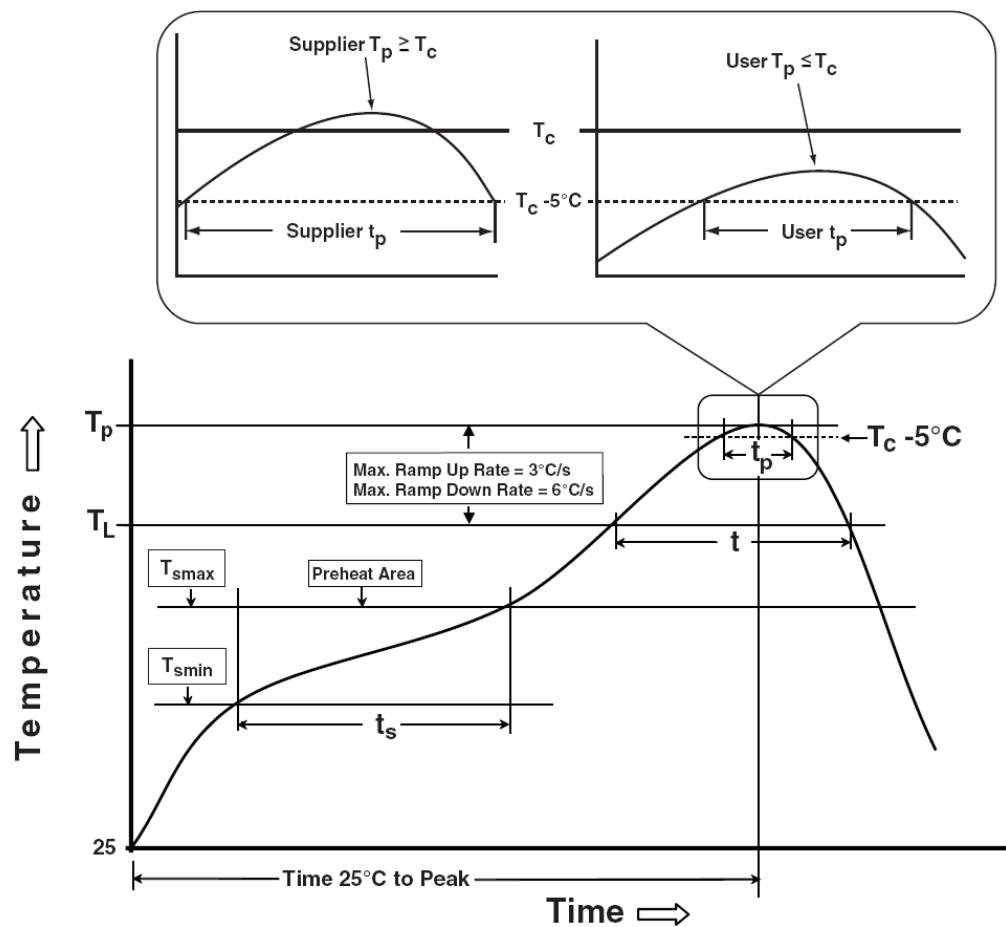
(mm)

Devices Per Unit

| Package Type | Unit | Quantity |
|--------------|-------------|----------|
| SOP-8 | Tape & Reel | 2500 |
| TDFN3x3-10 | Tape & Reel | 3000 |

Taping Direction Information**SOP-8****TDFN3x3-10**

Classification Profile



Classification Reflow Profiles

| Profile Feature | Sn-Pb Eutectic Assembly | Pb-Free Assembly |
|----------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------|------------------------------------|
| Preheat & Soak Temperature min (T_{smin}) Temperature max (T_{smax}) Time (T_{smin} to T_{smax}) (t_s) | 100 °C 150 °C 60-120 seconds | 150 °C 200 °C 60-120 seconds |
| Average ramp-up rate (T_{smax} to T_p) | 3 °C/second max. | 3°C/second max. |
| Liquidous temperature (T_L) Time at liquidous (t_L) | 183 °C 60-150 seconds | 217 °C 60-150 seconds |
| Peak package body Temperature (T_p)* | See Classification Temp in table 1 | See Classification Temp in table 2 |
| Time (t_p)** within 5°C of the specified classification temperature (T_c) | 20** seconds | 30** seconds |
| Average ramp-down rate (T_p to T_{smax}) | 6 °C/second max. | 6 °C/second max. |
| Time 25°C to peak temperature | 6 minutes max. | 8 minutes max. |

* Tolerance for peak profile Temperature (T_p) is defined as a supplier minimum and a user maximum.

** Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.

Table 1. SnPb Eutectic Process – Classification Temperatures (T_c)

| Package Thickness | Volume mm ³ | Volume mm ³ |
|----------------------|------------------------|------------------------|
| | <350 | ≥350 |
| <2.5 mm | 235 °C | 220 °C |
| ≥2.5 mm | 220 °C | 220 °C |

Table 2. Pb-free Process – Classification Temperatures (T_c)

| Package Thickness | Volume mm ³ | Volume mm ³ | Volume mm ³ |
|----------------------|------------------------|------------------------|------------------------|
| | <350 | 350-2000 | >2000 |
| <1.6 mm | 260 °C | 260 °C | 260 °C |
| 1.6 mm – 2.5 mm | 260 °C | 250 °C | 245 °C |
| ≥2.5 mm | 250 °C | 245 °C | 245 °C |

Reliability Test Program

| Test item | Method | Description |
|---------------|--------------------|------------------------------------------|
| SOLDERABILITY | JESD-22, B102 | 5 Sec, 245°C |
| HOLT | JESD-22, A108 | 1000 Hrs, Bias @ $T_j=125^\circ\text{C}$ |
| PCT | JESD-22, A102 | 168 Hrs, 100%RH, 2atm, 121°C |
| TCT | JESD-22, A104 | 500 Cycles, -65°C~150°C |
| HBM | MIL-STD-883-3015.7 | VHBM 2KV |
| MM | JESD-22, A115 | VMM 200V |
| Latch-Up | JESD 78 | 10ms, I_{tr} 100mA |

Customer Service

Anpec Electronics Corp.

Head Office :

No.6, Dusing 1st Road, SBIP,
Hsin-Chu, Taiwan, R.O.C.

Tel : 886-3-5642000
Fax : 886-3-5642050

Taipei Branch :

2F, No. 11, Lane 218, Sec 2 Jhongsing Rd.,
Sindian City, Taipei County 23146, Taiwan
Tel : 886-2-2910-3838
Fax : 886-2-2917-3838